CRATERS PRODUCED ON Al, Cu AND Au by Ar CLUSTER IMPACTS*

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ABSTRACT

Transmission electron microscopy has been used to observe craters produced on Al, Cu and Au at room temperature by the impact of Ar clusters. Irradiations were made at normal incidence with Ar clusters of either 100 or 1000 atoms having an energy of 100 keV. The probability of a cluster to make a crater decreases with increasing target atomic mass or density. At a given total energy, the probability of a cluster to make a crater increases with increasing cluster size. This increase in cratering rate with decreasing energy per atom in the cluster occurs because of greater energy deposition near the specimen surface due to increased rate of energy loss by individual atoms in the cluster.

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INTRODUCTION

Energetic beams of clusters containing up to several thousand gas atoms have become available [1]. The results of bombardment with such cluster beams are of scientific and potentially technological importance in fields of thin film growth, shallow implantations, SIMS and surface processing. It is well known that the impact of atomic clusters causes major topographical changes [2] and enhanced sputtering [3]. In some cases, cluster impacts result in smoothing, but the most striking of these changes is the production of craters on specimen surfaces. Craters on graphite [4] have been produced by clusters of C, Ar, N, O, Ga, CsI, Au and Ta. Cluster irradiations have also produced craters on Au and sapphire [5]. Visible craters range in diameter from 1 to 5 nm in diameter and appear to be as deep as wide. In this work transmission electron microscopy has been used to examine the surfaces of Al, Cu and Au after irradiation with Ar clusters of different sizes. Craters have been found in all cases.
EXPERIMENTAL

Transmission electron microscopy specimens of Al, Cu and Au were prepared by electrochemical jet thinning of well annealed, high purity disks to perforation at Argonne National Laboratory in the USA. The specimens were mounted in a stainless steel irradiation holder, and the assembly was sealed in a quartz tube filled with 1 atm of Ar and transported to Japan. After cluster-beam irradiation the specimen assembly was returned to Argonne National Laboratory where the specimens were removed and examined in a Hitachi H-9000 electron microscopy.

Ar cluster irradiations were performed at Kyoto University [1]. Cluster beams were produced by the adiabatic expansion of Ar at supersonic speed into high vacuum. The beam was collimated and then ionized by electron bombardment. Clusters were singly charged. After extraction, the cluster beam was accelerated to 100 keV. Cluster size was controlled by gas pressure in the source and electrostatic mass filtering. This results in a broad distribution of cluster sizes. Irradiations were made with cluster containing an average of either 100 or 1000 Ar atoms. Specimens were irradiated at room temperature to doses of $2 \times 10^{10}$ and $5 \times 10^{10}$ Ar clusters/cm². The cluster impacted the specimens at normal incidence.
RESULTS

Transmission electron microscopy (TEM) examination of the specimens after cluster irradiation at room temperature revealed that cluster impacts produced craters on the three materials irradiated. Figure 1 shows images of craters on Al produced by 100 keV clusters of 100 or 1000 Ar atoms. This pair of micrographs is typical of craters produced on Cu or Au by Ar clusters as well as craters produced by single heavy ions on Au [6]. Subsequent examinations show that the craters are stable at room temperature for periods longer than several months.

The number density of the craters produced by each irradiation on all three materials was determined from areas approximately ten times larger than shown in figure 1. For the irradiation dose range studied, the number of craters scaled with the cluster dose indicating that the cratering rate by cluster impacts was independent of dose for all materials studied. A linear accumulation of craters followed by a steady state density under continuous irradiation was also observed during in situ, single ion irradiation of a variety of metals [6,7]. The in situ observations of single ion irradiations revealed that single ion impacts can annihilate craters, even if a new crater is not produced, resulting in a saturation of the crater density at high dose. A cluster cratering rate that is independent of dose indicates that subsequent cluster impacts did not significantly annihilate existing craters and that the crater density has not begun to approach a saturation value. The linear rate of increase is determined by the cross section for a single impact to produce a crater, and the saturation value is determined by the ratio of the production cross section to the cross section for an impact to annihilate a crater. In order to remain in the linear domain and allow determination of the crater production rates during the current ex situ experiments, total cluster doses of less than 5 \(10^{10}\) cm\(^{-2}\) were used. In this case, only one or two percent of the surface was impacted by a cluster or covered by craters, and the
probability that a crater was annihilated during any irradiation is estimated to be less than one percent.

Although the images of craters are similar for all the materials studied, cluster impacts more readily produce craters on a light, low Z material such as Al than on a dense, high Z material such as Au. Cratering rates, the number of craters per cluster impact, are plotted in figure 2. The uncertainty in the results is greatest for Cu because of 1 to 10 nm size surface irregularities on the as-prepared specimens. TEM observations can not provide accurate information on the depth of craters and the amount of material affected, but indications from STM observations of craters on Au by single ion impacts suggest that craters are slightly less deep than their radius.

DISCUSSION

For a given energy and cluster size, the cratering rate decreases as the target density and atomic mass increases. This is counter to what has been observed for single ion impacts where the cratering rate increases with target density [7]. The different behaviors are due to the different rates of energy loss and different efficiencies to deposit large amounts of energy into small volumes at the specimen surface. Ranges of both single ions and recoiling target atoms in low density, low Z materials are too long for the irradiation to achieve the required density of energy deposition in a dense displacement cascade. On the other hand, the individual low-energy atoms in a cluster are unable to effectively penetrate dense, high Z materials. The result is that a single 100 keV Ar ion is more effective at making a dense cascade in Au than Al, while a 100 keV Ar cluster with 1 keV/Ar is more effective on Al than Au.
For a given target material and acceleration voltage, larger clusters are more efficient at making craters than smaller clusters, and these craters tend to have larger sizes. As the cluster size is increased at a fixed acceleration voltage, more target atoms will be directly affected by a cluster impact. Thus the probability for an impact event to generate a structure that remains on the surface increases with cluster size. This may also be viewed in terms of the energy per Ar atom in a cluster, which decreases with increasing cluster size at constant acceleration voltage. As the energy per Ar atom in a cluster increases (decreasing cluster size), the cratering rate for the materials studied decreases. The decrease is greatest for lower density materials, and in the limit of a single ion, cratering is observed during in situ irradiation of Au but not Al. Coupled to the production of craters on Au by single ion impacts is the ejection of Au nanoparticles with comparable sizes [6,8]. These nanoparticles make a significant contribution to the total sputtering yield.

Overall, these results indicate that craters are produced when an ion or cluster impact deposits a critical energy density that results in melting of a sufficiently large volume in the near surface region [7]. In most materials this requires between 1 and 2 eV per atom. This requires either a dense cascade produced by either a recoil from a single ion impact, such as can occur in Au but not in Al, or a high impact-energy density from a cluster, such as can be achieved on Al.
REFERENCES

FIGURES
Figure 1 TEM images of craters produced on Al by room temperature bombardment with clusters containing an average of 1000 Ar atoms. Two different doses are shown: a, $2 \times 10^{10}$ Ar/cm$^2$; and b, $5 \times 10^{10}$ Ar/cm$^2$.

Figure 2 The number of craters produced per Ar cluster impact as a function of the number of Ar atoms in the cluster for 100 keV irradiations.
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